TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

TK40A10K3

Switching Regulator Application

• Low drain-source ON resistance: $R_{DS (ON)} = 11.5 \text{ m}\Omega \text{ (typ.)}$

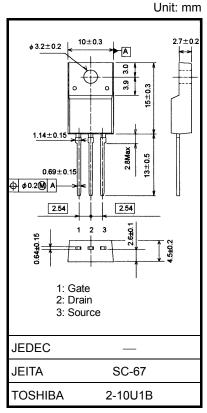
• High forward transfer admittance: |Y_{fS}| = 80 S

• Low leakage current: I_{DSS} = 10 μA (max) (V_{DS} = 100 V)

• Enhancement-mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	100	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC (Note 1) I _D	40	Α	
	Pulse (Note 1) I _{DP}	160	A	
Drain power dissipat	ion (Tc = 25°C)	PD	40	W	
Single pulse avalance	he energy (Note 2) E _{AS}	137	mJ	
Avalanche current		I _{AR}	40	Α	
Repetitive avalanche	energy (Note 3) E _{AR}	3.3	mJ	
Channel temperature)	T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

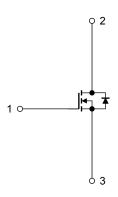
Note 1: Ensure that the channel & lead temperature does not exceed 150°C.

Note 2: $V_{DD} = 50$ V, $T_{ch} = 25^{\circ}$ C, L = 100 μ H, $I_{AR} = 40$ A, $R_G = 1$ Ω

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device. Handle with care.

Internal Connection



Electrical Characteristics (Ta = 25°C)

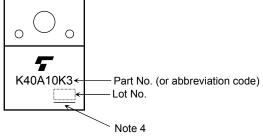
Chara	ecteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-OFF cu	rrent	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	_	_	10	μΑ
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	_		V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	65	_	_	
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source ON resistance		R _{DS} (ON)	V _{GS} = 10 V, I _D = 20 A	_	11.5	15	mΩ
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 20 A	40	80	_	S
Input capacitance		C _{iss}		_	4000	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 10V, V _{GS} = 0 V, f = 1 MHz	_	330	_	
Output capacitance		Coss			480		
Switching time	Rise time	t _r	V_{GS} 0 V V_{GS} 0 V $V_{DD} \approx 50$ V Duty \leq 1%, $t_{W} = 10$ μs	_	85	_	ns
	Turn-ON time	t _{on}		_	130		
	Fall time	t _f		_	70		
	Turn-OFF time	t _{off}		_	260		
Total gate charge (gate-source plus gate-drain)		Qg	V _{DD} ≈ 80 V, V _{GS} = 10 V, I _D = 40 A	_	85	_	nC
Gate-source charge 1		Q _{gs1}		_	20	_	
Gate-drain ("miller") charge		Q _{gd}			35	_	
Gate switch charge		Q_{SW}		_	40	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	_	_	_	40	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	160	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_	-0.9	-1.2	٧
Reverse recovery time	t _{rr}	$I_{DR} = 40 \text{ A}, V_{GS} = 0 \text{ V},$	_	55	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} / dt = 50 A / μs	_	55	_	nC

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Marking

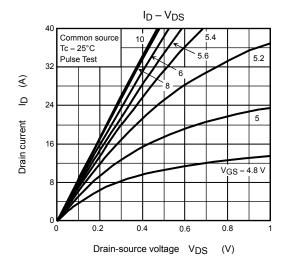


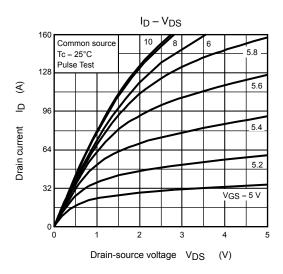
Note 4: A line under a Lot No. identifies the indication of product Labels.

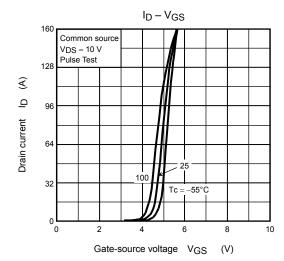
Not underlined: [[Pb]]/INCLUDES > MCV

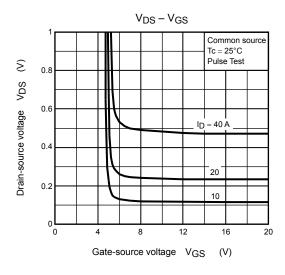
 $\label{thm:compatible} \mbox{Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$

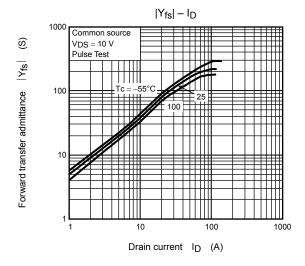
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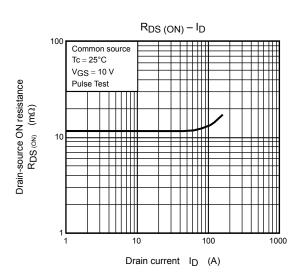




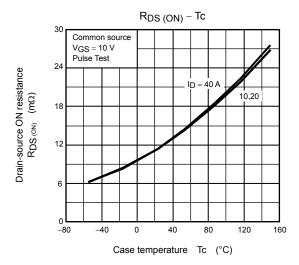


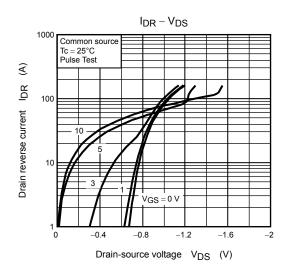


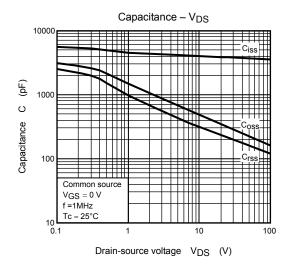


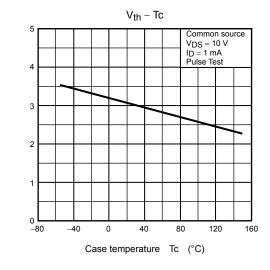


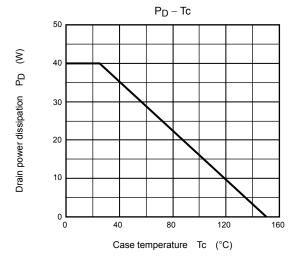
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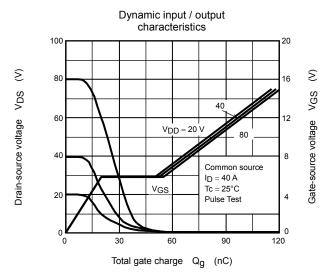






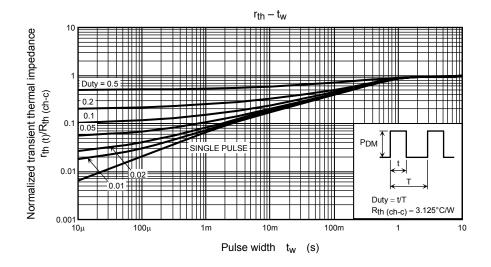


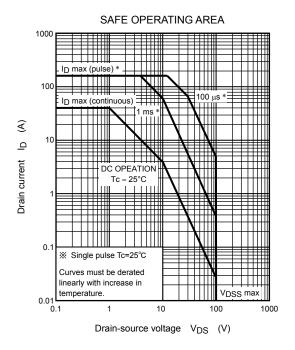


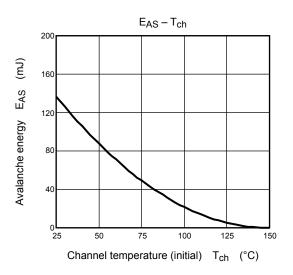


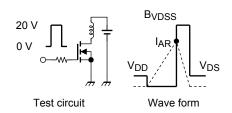
Vth (V)

Gate threshold voltage









$$R_G = 1~\Omega$$

$$V_{DD} = 50~V,~L = 100~\mu H$$

$$EAS = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$$

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